

MSR1560, MSRF1560

SWITCHMODE™ Soft Recovery Power Rectifier

These state-of-the-art devices are designed for boost converter or hard-switched converter applications, especially for Power Factor Correction application. It could also be used as a free wheeling diode in variable speed motor control applications and switching mode power supplies.

Features

- Soft Recovery with Low Reverse Recovery Charge (Q_{RR}) and Peak Reverse Recovery Current (I_{RRM})
- Epoxy meets UL 94 V-0 @ 0.125 in
- Low Forward Voltage
- Low Leakage Current
- High Temperature Glass Passivated Junction
- Pb-Free Package is Available*

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	600	V
Average Rectified Forward Current (At Rated V_R , $T_C = 125^\circ\text{C}$)	I_O	15	A
Peak Repetitive Forward Current (At Rated V_R , Square Wave, 20 kHz, $T_C = 125^\circ\text{C}$)	I_{FRM}	30	A
Non-Repetitive Peak Surge Current (Surge applied at rated load conditions, halfwave, single phase, 60 Hz)	I_{FSM}	100	A
Operating Junction and Storage Temperature Range	T_J , T_{stg}	-65 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Parameter	Symbol	Value	Unit
MSR1560: Thermal Resistance Junction-to-Case Junction-to-Ambient	$R_{\theta JC}$ $R_{\theta JA}$	1.6 72.8	$^\circ\text{C/W}$
MSRF1560: Thermal Resistance Junction-to-Case Junction-to-Ambient	$R_{\theta JC}$ $R_{\theta JA}$	4.25 75	$^\circ\text{C/W}$

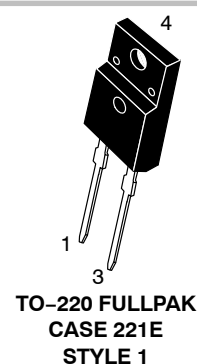
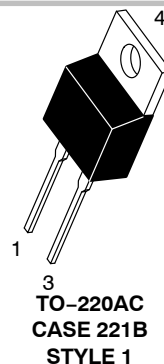
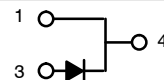
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



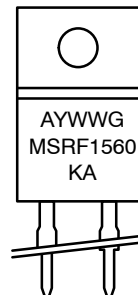
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SOFT RECOVERY POWER RECTIFIER 15 AMPERES, 600 VOLTS



MARKING DIAGRAMS



A = Assembly Location
Y = Year
WW = Work Week
G = Pb-Free Package
KA = Diode Polarity

ORDERING INFORMATION

Device	Package	Shipping
MSR1560	TO-220AC	50 Units/Rail
MSR1560G	TO-220AC (Pb-Free)	50 Units/Rail
MSRF1560G	TO-220FP (Pb-Free)	50 Units/Rail

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Value		Unit
Instantaneous Forward Voltage (Note 1) ($I_F = 15\text{ A}$) Maximum Typical	V_F	$T_J = 25^\circ\text{C}$	$T_J = 150^\circ\text{C}$	V
		1.8 1.5	1.4 1.2	
Instantaneous Reverse Current ($V_R = 600\text{ V}$) Maximum Typical	I_R	$T_J = 25^\circ\text{C}$	$T_J = 150^\circ\text{C}$	μA
		15 0.4	5000 100	
Reverse Recovery Time (Note 2) ($V_R = 30\text{ V}$, $I_F = 1\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$) Maximum Typical	t_{rr}	$T_J = 25^\circ\text{C}$	$T_J = 100^\circ\text{C}$	ns
		45 35	65 54	
Typical Recovery Softness Factor ($V_R = 30\text{ V}$, $I_F = 1\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$)	$s = t_b/t_a$	0.67	0.74	
Typical Peak Reverse Recovery Current ($V_R = 30\text{ V}$, $I_F = 1\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$)	I_{RRM}	2.3	3.2	A
Typical Reverse Recovery Charge ($V_R = 30\text{ V}$, $I_F = 1\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$)	Q_{RR}	31	78	nC

1. Pulse Test: Pulse Width $\leq 380\text{ }\mu\text{s}$, Duty Cycle $\leq 2\%$
2. T_{RR} measured projecting from 25% of I_{RRM} to zero current

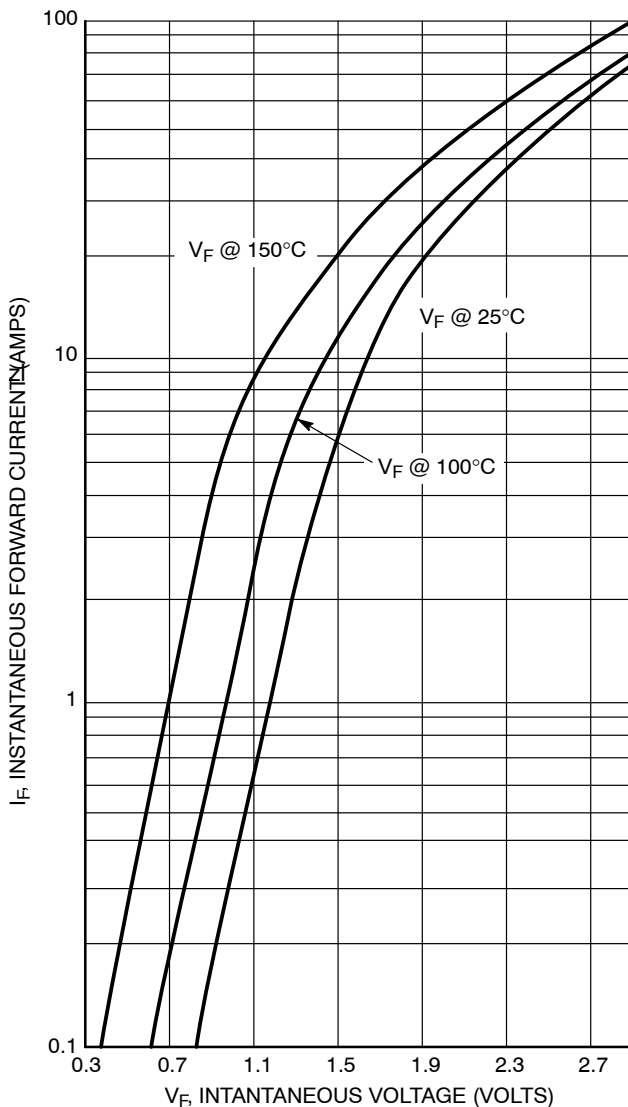


Figure 1. Maximum Forward Voltage

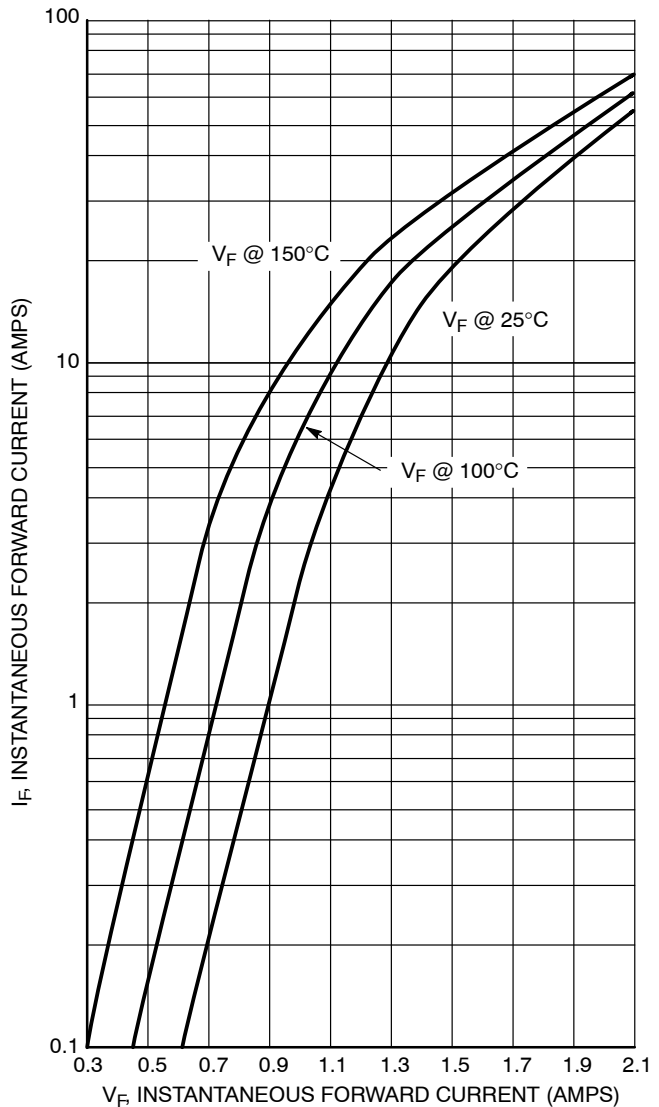


Figure 2. Typical Forward Voltage

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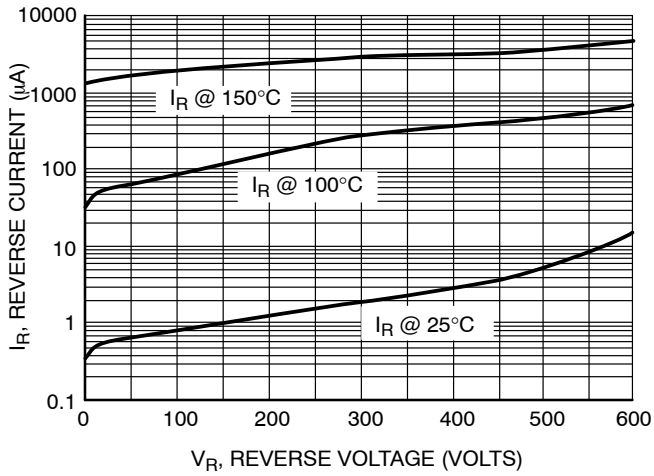


Figure 3. Maximum Reverse Current

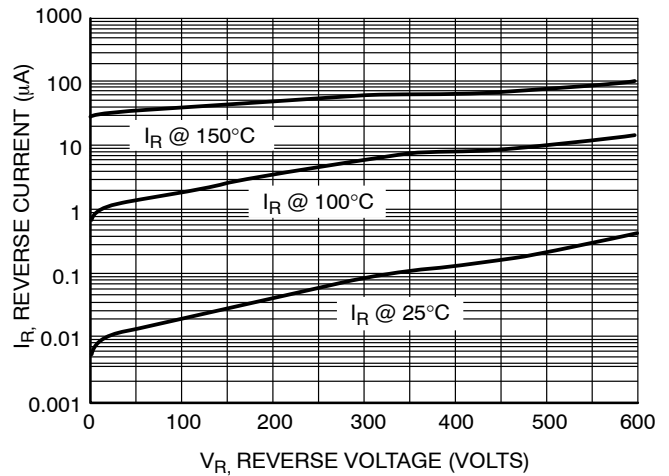


Figure 4. Typical Reverse Current

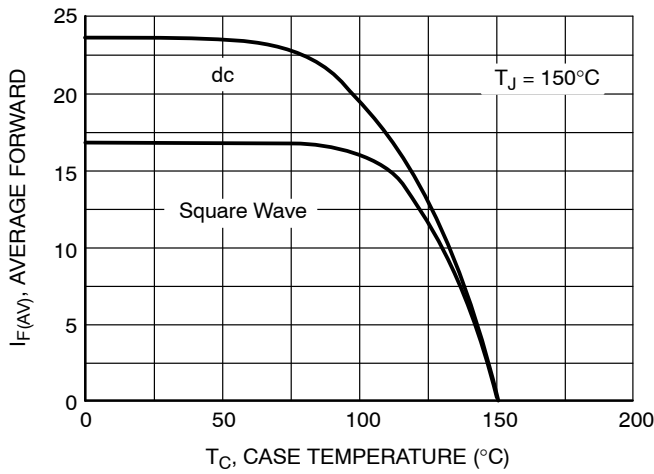


Figure 5. Current Derating

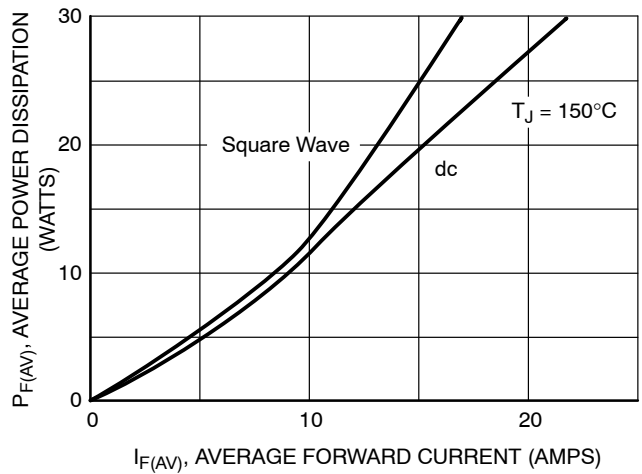


Figure 6. Power Dissipation

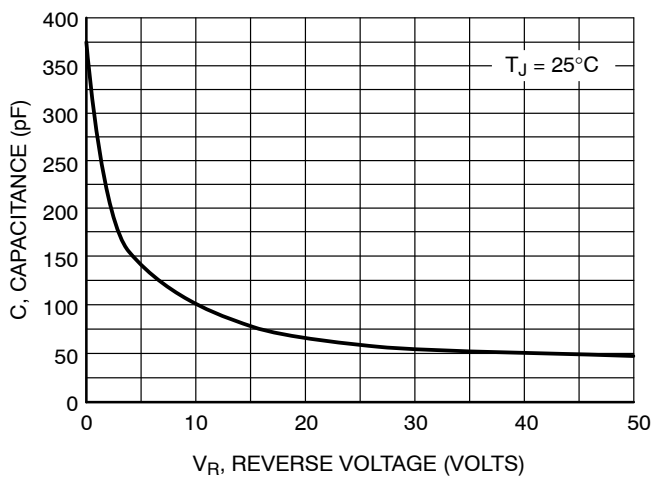


Figure 7. Maximum Capacitance

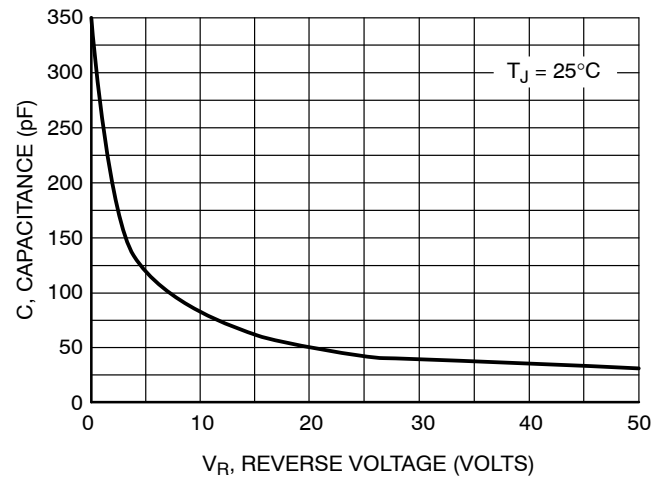


Figure 8. Typical Capacitance

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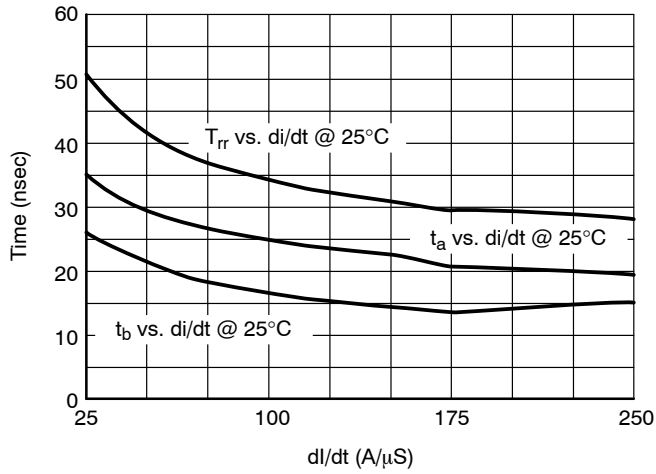


Figure 9. Typical Trr vs. di/dt

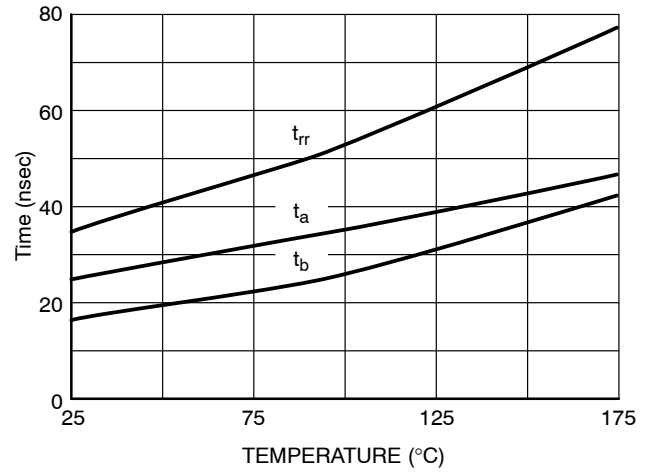


Figure 10. Typical Trr vs. Temperature

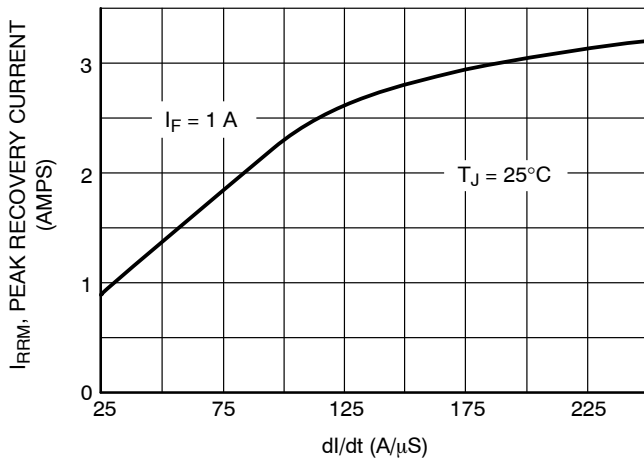


Figure 11. Typical Peak Reverse Recovery Current

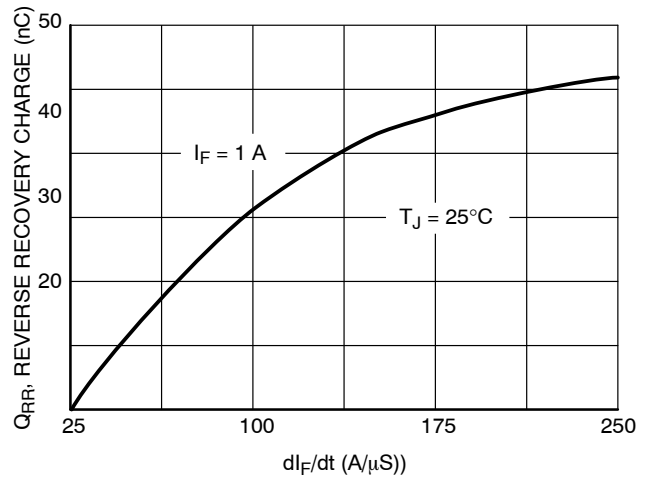


Figure 12. Typical Reverse Recovery Charge

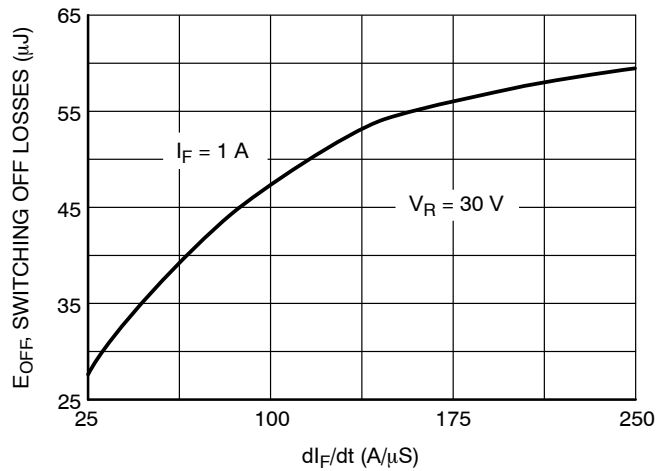


Figure 13. Typical Switching Off Losses

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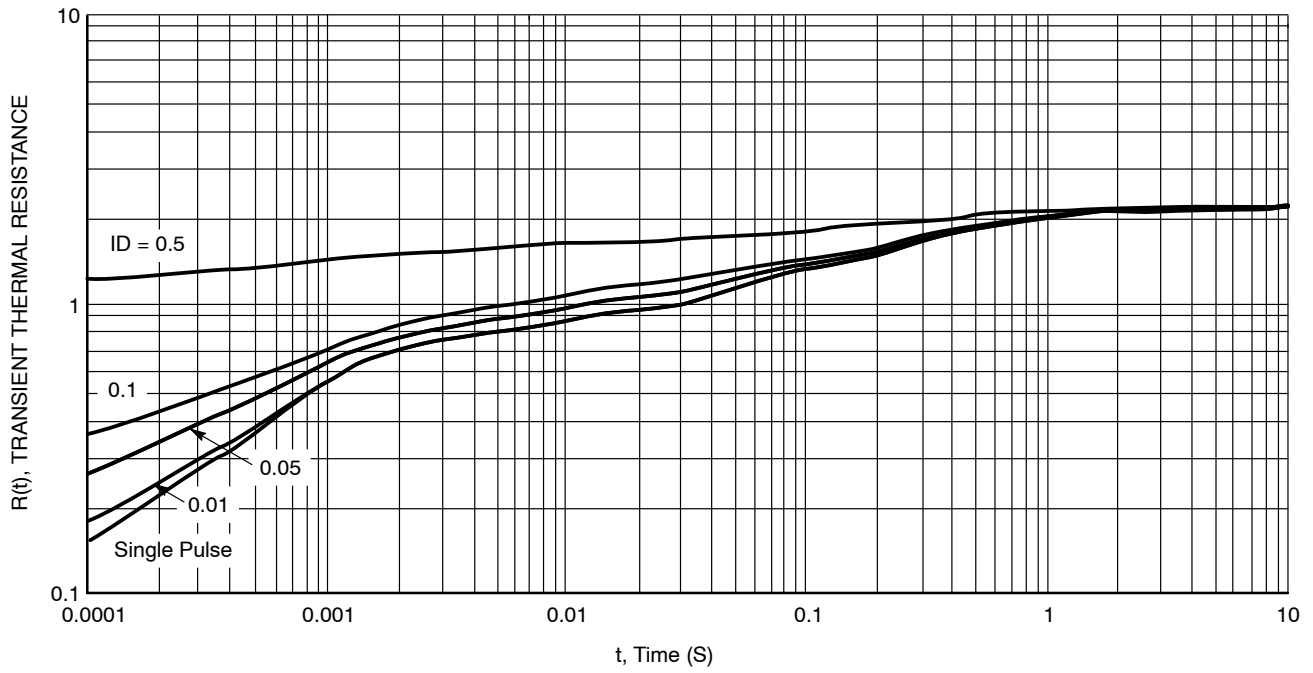


Figure 14. Transient Thermal Response

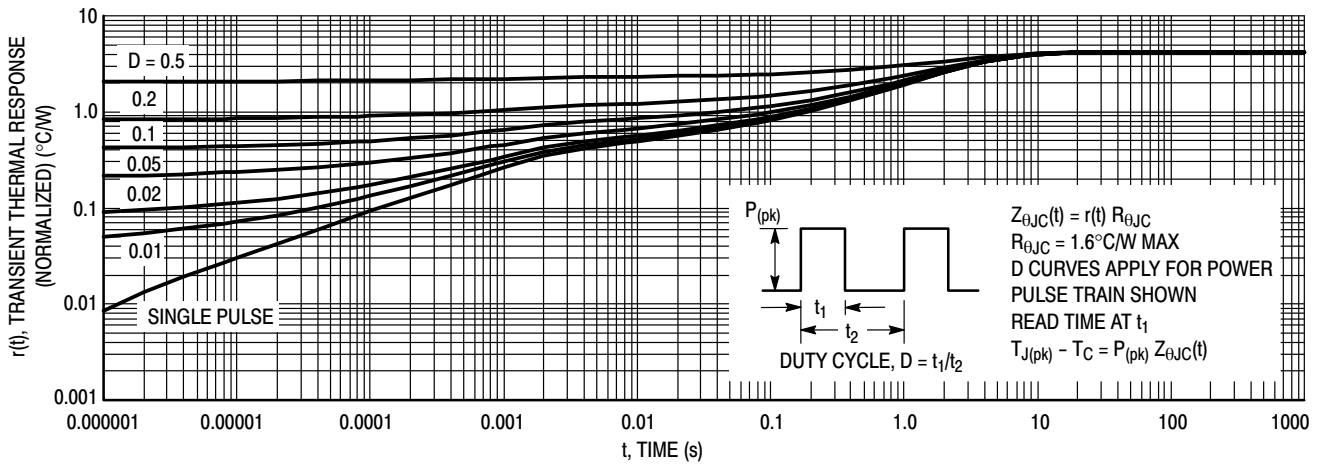


Figure 15. Thermal Response, (MSRF1560) Junction-to-Case ($R_{\theta JC}$)

MSR1560, MSRF1560

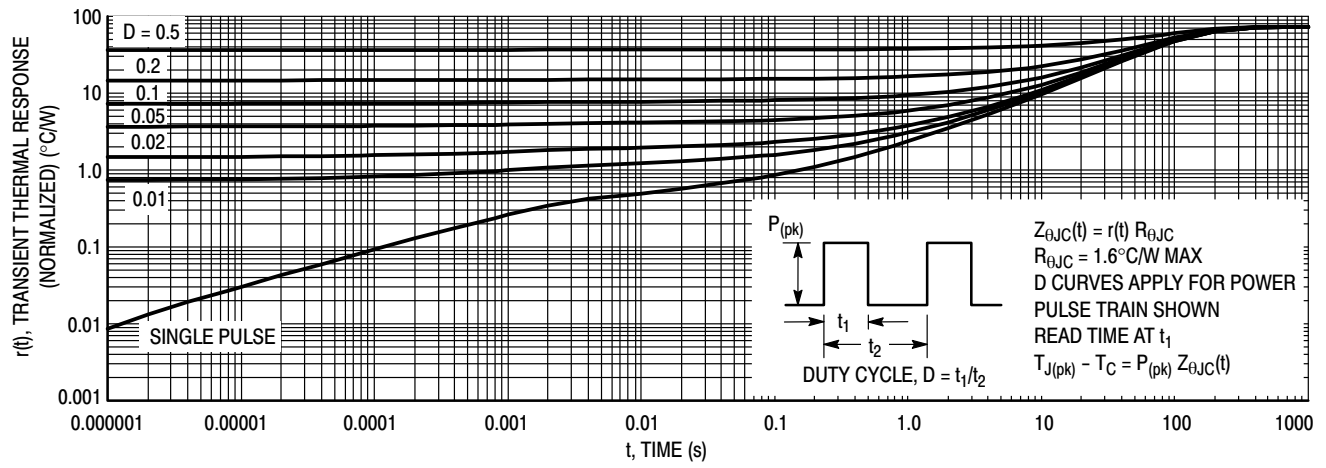
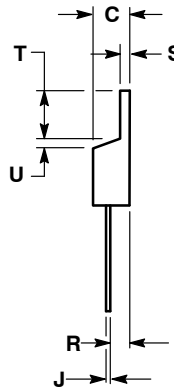
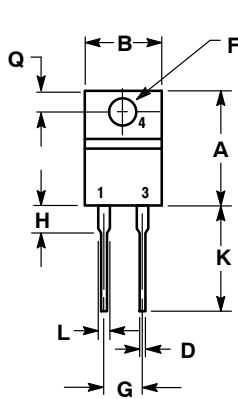


Figure 16. Thermal Response, (MSRF1560) Junction-to-Ambient ($R_{\theta JA}$)

MSR1560, MSRF1560

PACKAGE DIMENSIONS

TO-220 TWO-LEAD CASE 221B-04 ISSUE E

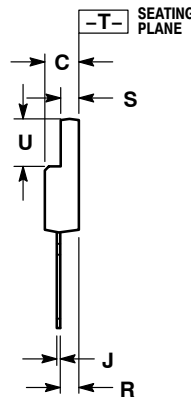
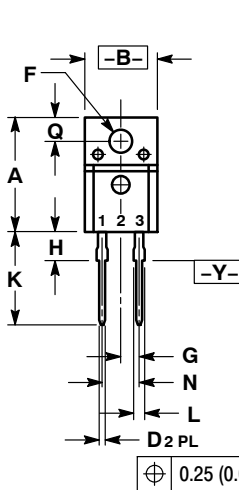


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.595	0.620	15.11	15.75
B	0.380	0.405	9.65	10.29
C	0.160	0.190	4.06	4.82
D	0.025	0.035	0.64	0.89
E	0.142	0.161	3.61	4.09
F	0.190	0.210	4.83	5.33
G	0.110	0.130	2.79	3.30
H	0.014	0.025	0.36	0.64
I	0.500	0.562	12.70	14.27
J	0.045	0.060	1.14	1.52
K	0.100	0.120	2.54	3.04
L	0.080	0.110	2.04	2.79
M	0.045	0.055	1.14	1.39
N	0.235	0.255	5.97	6.48
O	0.000	0.050	0.000	1.27

- STYLE 1:
1. CATHODE
 2. N/A
 3. ANODE
 4. CATHODE

TO-220 FULLPAK, 2-LEAD CASE 221E-01 ISSUE A



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.617	0.633	15.67	16.07
B	0.392	0.408	9.96	10.36
C	0.177	0.193	4.50	4.90
D	0.024	0.039	0.60	1.00
E	0.121	0.129	3.08	3.28
F	0.100 BSC		2.54 BSC	
G	0.117	0.133	2.98	3.38
H	0.018	0.025	0.45	0.64
I	0.499	0.562	12.68	14.27
J	0.045	0.060	1.14	1.52
K	0.200 BSC		5.08 BSC	
L	0.122	0.138	3.10	3.50
M	0.101	0.117	2.56	2.96
N	0.092	0.108	2.34	2.74
O	0.255	0.271	6.48	6.88

- STYLE 1:
1. CATHODE
 2. N/A
 3. ANODE

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